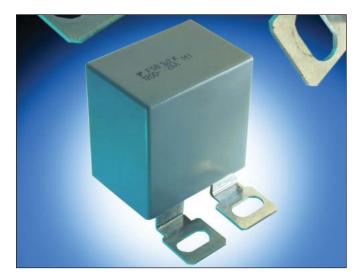
APD Wedlum Power Pilm Capacitors watermark



FSB (RoHS Compliant)



GENERAL DESCRIPTION

Metallized polypropylene dielectric capacitor with controlled self-healing.

Reinforced metallization developed for high impulse currents.

APPLICATIONS

- IGBT protection
- IGBT clamping

PACKAGING MATERIAL

• Plastic case backfilled with thermosetting resin

HOW TO ORDER

FSB	1 ⊺	6 ⊤	U ⊤	0154	J ⊤	
Series	Case Size 1 = PO Style 2 = 18 Style 3 = 19 Style 4 = 26 style 5 = R28 Style (2 terminal) CTRICAL CH	Dielectric 6 = Polypropylene ARACTERIS	Voltage Code B = 850Vdc U = 1200Vdc M = 1600Vdc N = 2000Vdc	Сарасіtалсе Соde 0 + pF code 0154 = 0.15µF 0334 = 0.33µF 0255 = 2.5µF etc.	Capacitance Tolerances $J = \pm 5\%$ $K = \pm 10\%$ (Case size 6 only)	Voltage Range = 2 Terminal JC = 4 Terminal (Case Size 5 option only)

Capacitance Range C _n	0.10µF to 2.5µF
Tolerance on C _n	±5%: FSB15 ±10%: FSB6
Rated DC Voltage Vndc	850 to 2000 V
Stray Inductance	≤ 25 nH
RMS Current	I _{rms} max. = up to 28A The currents shown in the tables are maximum. It is necessary to maintain operation within the maximum temperature of the dielectric 85°C. See "Hot spot temperature calculation"
Insulation Resistance	R _i x C ≥ 30,000 s
Impulse Current	I ² .t max. = up to 1.69 A ² s Spikes or peak currents in the capacitors may cause a deterioration of the bonding between the metallization and the connections. These bonds are capable of withstanding only a limited amount of energy for each spike. The table shows the maximum energy permitted in the form (I ² .t), where I is in Amperes, and t is in seconds.
Note: The formula (12 t) replaces du/	dt which is less easy to use as it is not an expression of energy $(I - C dy/dt)$

Note: The formula (l^2 .t) replaces dv/dt which is less easy to use as it is not an expression of energy (l = C.dv/dt). This type of capacitor has been designed to withstand high (I².t) values.

Variation of Capacitance with Temperature	$\frac{\Delta C}{C} \le \pm 2\%$ between -40 and +85°C
Climatic Category	40/085/56 (IEC 68)
Test Voltage Between Terminals @ 25°C	1.6 V _n dc during 10s
Withstanding Voltage Between Terminals	
and Case @ 25°C	@ 3 kVrms @ 50Hz during 1 min.



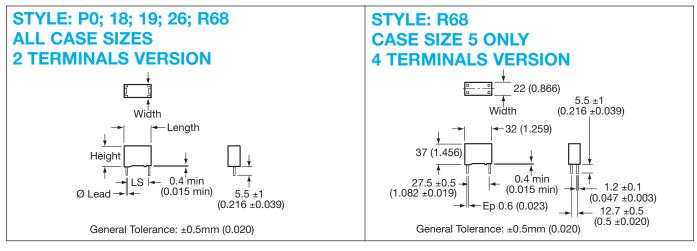
http://www.kttic.c&m

KTTIC http://www.kttic.com Medium Power Film Capacitors



FSB (RoHS Compliant)

GENERAL DESCRIPTION



DIMENSIONS: millimeters (inches)

Case Size	Case Style	Length mm ±0.40 (inches)	Width mm ±0.40 (inches)	Height mm ±0.30 (inches)	Dimensions lead mm +10% -0.05 (inches)	LS mm ±0.40 (inches)
1	PO	31.1 (1.230)	13.0 (0.051)	22.4 (0.880)	Ø 0.80 (0.031)	27.5 (1.083)
2	18	31.1 (1.230)	14.6 (0.580)	25.7 (1.010)	Ø 0.80 (0.031)	27.5 (1.083)
3	19	31.1 (1.230)	17.3 (0.068)	29.8 (1.170)	Ø 0.80 (0.031)	27.5 (1.083)
4	26	31.1 (1.230)	20.8 (0.820)	31.3 (1.230)	Ø 1.00 (0.039)	27.5 (1.083)
5	R68 2 Terminals Version	32.5 (1.280)	22.0 (0.870)	37.0 (1.460)	Ø 1.00 (0.039)	27.5 (1.083)
5	R68 4 Terminals Version	32.5 (1.280)	22.0 (0.870)	37.0 (1.460)	1.20 x 0.60 (0.047 x 0.023)	27.5 (1.083)

RATINGS AND PART NUMBER REFERENCE

Part Number	Capacitance (µF)	Case Style	(l2t) (A ² s)	Irms (A)	Rs (mΩ)	Rth (hotspot/amb.)	Typical Weight (g)
	U _N dc =	1200V Vpeak = ⁻	600V Vrms = 560V Vs = 2000V (Voltage Code U)				
FSB16U0154J	0.15	PO	0.05	3	14.3	45.9	15
FSB26U0274J	0.27	18	0.15	7.6	8.4	36.8	20
FSB36U0394J	0.39	19	0.31	11	6.2	32.2	25
FSB46U0474J	0.47	26	0.41	12	5.6	29.4	32
FSB56U0684J	0.68	R68 (2 terminals)	0.94	12	3.8	23.7	40
FSB56U0684JJC	0.68	R68 (4 terminals)	0.94	16.7	3.8	23.7	40
	U _N dc =	1600V Vpeak =	2000V Vrms =	630V Vs = 230	0V (Voltage C	ode M)	
FSB16M0134J	0.13	PO	0.05	4.6	13.3	44.9	15
FSB26M0184J	0.18	18	0.1	6.4	9.9	35.9	20
FSB36M0244J	0.24	19	0.18	8.5	7.8	32.4	25
FSB46M0334J	0.33	26	0.35	11.7	5.6	28.6	32
FSB56M0434J	0.43	R68 (2 terminals)	0.59	12	4.6	23.8	40
FSB56M0434JJC	0.43	R68 (4 terminals)	0.59	15.2	4.6	23.8	40
U,dc = 2000V Vpeak = 2400V Vrms = 700V Vs = 2600V (Voltage Code N)							
FSB16N0104J	0.1	PO	0.05	4.2	14.3	44.6	15
FSB26N0134J	0.13	18	0.08	5.5	11.3	35.7	20
FSB36N0184J	0.18	19	0.15	7.6	8.5	32.1	25
FSB46N0224J	0.22	26	0.22	9.3	6.8	29.1	32
FSB56N0304J	0.3	R68 (2 terminals)	0.41	12	5.3	23.8	40
FSB56N0304JJC	0.3	R68 (4 terminals)	0.41	12.7	5.3	23.8	40



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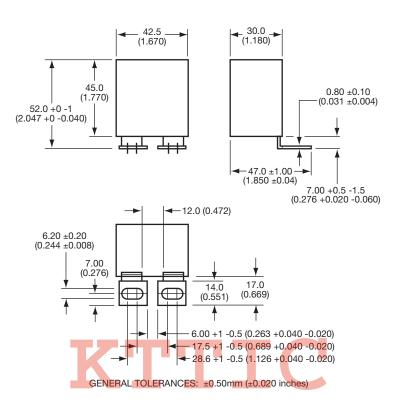


FSB (RoHS Compliant)

CASE SIZE 6

Plastic case resin filled

Dimensions: millimeters (inches)



RATINGS AND PART NUMBER REFERENCE

Part Number	Capacitance (µF)	(l2t) (A ² s)	I _{rms max.} (A)	R _s (mΩ)	R _{th} (°C/W)	Typical Weight (g)
	FSB 850V	V _n dc = 850V V _{peak} =	1200V V _{rms} = 45	0V V _S = 1500V (Voltage Code B)	
FSB66B0205K	2	0.99	25	3.4	19.1	87
FSB66B0225K	2.2	1.19	28	3.1	18.6	87
FSB66B0255K	2.5	1.54	28	2.7	17.8	87
	FSB 1200V	Vndc = 1200V Vpeak	= 1600V V _{rms} = 5	60V V _S = 2000V	(Voltage Code U)	•
FSB66U0105K	1	1.47	25	3.6	17.2	87
FSB66U0125K	1.2	1.69	26	3.4	17.5	87
FSB66U0155K	1.5	1	26	3.4	17.5	87
	FSB 2000V	Vndc = 2000V Vpeak	= 2400V V _{rms} = 7	00V V _S = 2600V	(Voltage Code N)	•
FSB66N0474K	0.47	0.41	22	6.3	19.4	87
FSB66N0564K	0.56	0.62	23	5.2	17.9	87
FSB66N0684K	0.68	0.91	24	4.4	17.3	87

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Medium Power Film Capacitors



FSB (RoHS Compliant)

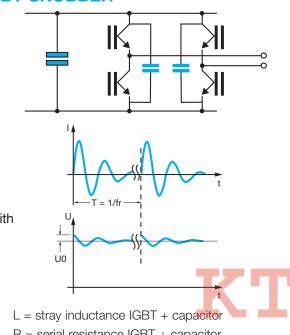
STANDARDS

IEC 61071-1, IEC 61071-2: Power electronic capacitors

TANGENT OF LOSS ANGLE (TANôo) FOR POLYPROPYLENE DIELECTRIC

Polypropylene has a constant dielectric loss factor of 2x10⁻⁴ irrespective of temperature and frequency (up to 1 MHz).

IGBT SNUBBER



R = serial resistance IGBT + capacitor

HOT SPOT TEMPERATURE CALCULATION

See Hot Spot Temperature, page 3.

$$\theta_{\text{hot spot}} = \theta_{\text{ambient}} + (P_{d} + P_{t}) \times R_{th}$$

with
$$P_d$$
 (Dielectric losses) = Q x tg δ_0

 \Rightarrow [$\frac{1}{2} \times C_n \times (V_{ripple peak to peak})^2 \times f$] x (2 x 10⁻⁴)

 P_t (Thermal losses) = $R_s \times (I_{rms})^2$

Rth : Rth ambient / hot spot in °C/W

where	C _n in Farad	I _{rms} in Ampere	f in Hertz
	V in Volt	R _s in Ohm	θ in °C

Due to the design of the capacitor and its technology, the thermal impedance between the terminations and the core of the capacitor is low, it is necessary to take care that the capacitor is never overheated by use of wrongly sized connections.

Do not use the capacitor as a heat sink.

Due to the complexity of the IGBT / capacitor thermal exchanges, we recommend that thermal measurements shall be made on the different components. We would be pleased to advise you on specific applications.

WORKING TEMPERATURE

(according to the power to be dissipated) -40°C to +85°C

MARKING

TPC logo Capacitance and tolerance in clear Nominal DC voltage in clear RMS current in clear Date of manufacture (IEC coding)

$$Ieff = \sqrt{\left[\frac{C\beta_{0}^{2} \times U_{0}}{2j\beta}\right]^{2} \times \frac{1}{T} \times \left[\frac{e^{-2\alpha \times T}}{\beta^{2} + \alpha^{2}} \times \left[\beta \sin(2\beta \times T) - \alpha \times \cos(2\beta \times T)\right] + \frac{1}{\alpha} \times e^{-2\alpha \times T} + \frac{\alpha}{\beta^{2} + \alpha^{2}} - \frac{1}{\alpha}\right]}$$

with $\beta 0 = \sqrt{\frac{1}{LC}}; \ \alpha = \frac{R}{2L}; \ \beta = \sqrt{\beta_{0}^{2} - \alpha^{2}}$

With